



Toward quantum confinement in Bi-based thermoelectric materials

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Accepted for publication on 11th April 2015

The potential for nanowires and quantum wells to improve thermoelectric (TE) performance via quantum confinement has been theorized since 1993, with proposed $ZT > 10$ for 0.5 nm diameter Bi_2Te_3 wires¹. However, such dimensionality is nearly impossible to grow; all Bi-based nanowire studies report ZT 's below bulk values. Indeed, reports with $ZT \geq 1$ from thin film superlattices² and nanostructured bulk materials³ were achieved via phonon engineering, not quantum confinement.

Reviewing the Bi-based nanowire literature reveals that crystalline quality, and therefore electron transport, has been greatly ignored. Hence, we studied growing high-crystalline quality Bi, Bi_2Te_3 , and $\text{Bi}_x\text{Sb}_{1-x}$ nanowires⁴⁻⁶. However, measuring transport properties from Bi-based nanowires is challenging: reports are few and our efforts were inconclusive. I will discuss the importance of nanowire crystallization and the difficulties making electrical and thermal contacts.

We are now approaching quantum confinement in a novel manner starting with high-crystalline quality thin films of a single-phase Bi-based material. I will report on the correlation of TE properties with structural quality, which we believe to be the starting point for creating the nanoscale dimensionality critical to observing quantum confinement via post-growth fabrication processes.

This work is supported by the Laboratory Directed Research and Development program at Sandia National Laboratories. Sandia National Laboratories is a multi-program laboratory managed and operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin Corporation, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000.

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Keywords: thermoelectric; quantum confinement; bismuth; nanowire; crystallinity